



Trench IGBT Platform Featuring PT (Punch Through) and FS (Field Stop) Technologies in Bare Die



KEY BENEFITS

- Offering includes one Trench PT and six Trench FS IGBTs
 - Low collector-to-emitter voltages down to 1.07 V at 50 % rated current and +125 °C provide extremely low conduction losses
 - Fast and soft turn-on and turn-off reduce switching losses and power consumption
- Soft turn-off reduces peak overvoltages, extends power ratings, and simplifies circuit layouts
 - Trench PT devices optimized for low switching frequencies to 1 kHz
 - Trench FS IGBTs offer 6 μ s short circuit rating and high operating temperature to +175 °C
 - Optimized for use with Vishay's new FRED Pt[®] Gen 4 Ultrafast soft diodes

APPLICATIONS

- Motor drives, UPS, solar inverters, and welding machine inverters
- Single- and three-phase inverters, power factor correction (PFC) circuits, and full- and half-bridge DC/DC converters

RESOURCES

- Datasheets: see next page for list of datasheets featured in this product sheet
- For technical questions, contact diewafer@vishay.com
- Material categorization: For definitions of compliance, please see <http://www.vishay.com/doc?99912>





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Vishay Semiconductors' Trench PT IGBTs, featuring a negative temperature coefficient for low collector-to-emitter voltages down to 1.07 V at 50 % rated current and +125 °C, provide extremely low conduction losses for applications with low switching frequencies to 1 kHz. With their Trench construction, the devices offer a smaller size than planar IGBTs, providing higher current density and lower thermal resistance, without compromising performance and reliability.

Vishay's Trench FS devices reduce conduction losses with their low collector-to-emitter saturation voltage down to 1.4 V at full current and 25 °C, while also providing fast and soft switching for reduced power consumption and low turn-on and turn-off losses. In addition, the devices' soft turn-off reduces peak overvoltages, extends power ratings, and simplifies circuit layouts. Offering a robust design, the FS IGBTs feature a high operating temperature to +175 °C, while their 6 μs short circuit rating time allows for safe and reliable operation under extreme load and failure conditions. The devices' low and positive temperature coefficient of the saturation voltage enables simple paralleling.

Both Trench PT and Trench FS IGBTs are optimized for use in power modules with Vishay's new FRED Pt Gen 4 Ultrafast soft diodes, where the devices will offer exceptionally low EMI and plug-and-play reliability.

IGBT PLATFORM TECHNOLOGY						
PART NUMBER	V_{CE} (V)	I_C (A)	$\frac{V_{CE(ON)}}{V_{CESAT}}$ (V)	TECHNOLOGY	DIE SIZE (MM)	DIE TYPE
VS-GC200A060LC	600	200	1.34	Trench PT	12.7 x 10.3	Sawn
VS-GC200A060LB	600	200	1.34	Trench PT	12.7 x 10.3	Unsawn
VS-GC200C060TC	600	200	1.45	Trench FS	10.3 x 9.8	Sawn
VS-GC200C060TB	600	200	1.45	Trench FS	10.3 x 9.8	Unsawn
VS-GC200C065TC	650	200	1.6	Trench FS	10.3 x 9.8	Sawn
VS-GC200C065TB	650	200	1.6	Trench FS	10.3 x 9.8	Unsawn
VS-GC030C060TC	600	30	1.5	Trench FS	3.5 x 4.3	Sawn
VS-GC030C060TB	600	30	1.5	Trench FS	3.5 x 4.3	Unsawn
VS-GC030C065TC	650	30	1.55	Trench FS	3.5 x 4.3	Sawn
VS-GC030C065TB	650	30	1.55	Trench FS	3.5 x 4.3	Unsawn
VS-GC240C060TC	600	240	1.4	Trench FS	12.6 x 10.3	Sawn
VS-GC240C060TB	600	240	1.4	Trench FS	12.6 x 10.3	Unsawn
VS-GC240C065TC	650	240	1.55	Trench FS	12.6 x 10.3	Sawn
VS-GC240C065TB	650	240	1.55	Trench FS	12.6 x 10.3	Unsawn

For more information on Vishay Semiconductors Trench PT IGBTs, please contact diewafer@vishay.com

Данный компонент на территории Российской Федерации

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<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9